

# 2017 *mini@sic* Europractice MPW runs Schedule and Prices

Accessible for universities & research institutes  
Version 170803- v15

[www.europractice-ic.com](http://www.europractice-ic.com)

*mini@sic*

Through the *mini@sic* program the EUROPRACTICE IC Service is offering special MPW prototyping conditions to stimulate Academia and publicly funded Research Institutes to prototype small ASIC designs for education or publicly funded research. Through Multi Project Wafer Services, the high cost of a prototype run (masks and wafers) is shared amongst several customers. However for student education or PhD research programs the minimum prototyping charges are still too high. By introducing the *mini@sic* concept on MPW runs EUROPRACTICE is offering considerably lower minimum prototyping charges for small ASIC designs. **Academia and Research Institutes will have the possibility to prototype small designs at low prices on selected MPW runs.**

## ON Semiconductor (formerly AMIS)

	J	F	M	A	M	J	J	A	S	O	N	D
ON Semi 0.7µ C07M-D 2M/1P & ON Semi 0.7µ C07M-A 2M/1P/Pdiff/HR	16		27			5		14		30		
ON Semi 0.35µ C035U 4M (3M & 5M optional) only thick top metal	30			17			3		18			4
ON Semi 0.7µ C07M-I2T100 100 V - 2M & 3M options	16		27			5		14		30		
ON Semi 0.35µ C035 - I3T80U 80 V 4M (3M & 5M optional) only thick top metal	2			3			10			9		
ON Semi 0.35µ C035 - I3T50U 50 V 4M - 3M optional (5M on special request)			6		29				4			4
ON Semi 0.35µ C035 - I3T50U (E) 50 V 4M - 3M optional (5M on special request)			6		29				4			4
ON Semi 0.35µ C035 - I3T25U 3.3/25 V 4M (3M & 5M optional) only thick top metal	30			17			3		18			4

## ams

	J	F	M	A	M	J	J	A	S	O	N	D
ams 0.35µ CMOS C35B4C3 4M/2P/HR/5V IO				24				7			20	
ams 0.35µ CMOS C35OPTO 4M/2P/5V IO				24				7			20	
ams 0.35µ HV CMOS H35B4D3 120V 4M					2					30		
ams 0.35µ SiGe-BiCMOS S35 4M/4P						6						11
ams 0.18µ CMOS aC18 6M/1P/MIM/1.8V/5V		20						21			27	
ams 0.18µ HV CMOS aH18 50V/20V/5V/1.8V/6M/MIM								21			27	
Bottom Anti Reflective Coating (BARC) Diode for ams 0.35µ CMOS C35OPTO 4M/2P/5V IO				24				7			20	
Wafer Level Chip Scale Package for ams 0.35µ CMOS C35B4C3 4M/2P/HR/5V IO				24				7			20	

Note: Customers making use of WLSCP have to send in their design gds file two weeks before the indicated deadline

## IHP

	J	F	M	A	M	J	J	A	S	O	N	D
IHP SGB25V 0.25µ SiGe:C Ft=75GHz@BVCEO 2.4V				21				4				
IHP SG25H3 0.25µ SiGe:C Ft/Fmax= 110/180GHz 5M/MIM	30							4				
IHP SG25H4 0.25µ SiGe:C Ft/Fmax= 200/220GHz 5M/MIM	30			21				4				
SG25H_EPIC (based on SG25H4)										20		
IHP SG13S SiGe:C Bipolar/Analog/CMOS/RF-MEMS Ft/Fmax= 250/300GHz 7M/MIM			17					18			24	
IHP SG13C SiGe:C CMOS 7M/MIM			17					18			24	
IHP SG13G2 SiGe:C Bipolar/Analog/RF-MEMS Ft/Fmax= 300/500GHz 7M/MIM			17					18			24	
IHP SG25 PIC (Photonics, Ge Photo-diode, BEOL)				7								

Bumping available for all IHP technologies with extra charge, limited to 200 bumps

**Important Note:** Dates are registration deadlines after which designs cannot enter this MPW run anymore. Final GDSII file must be submitted within 10 days after this date.

## X-FAB

	J	F	M	A	M	J	J	A	S	O	N	D
XH018 0.18µ HV NVM CMOS E-FLASH *				24						30		
XT018 0.18µ HV SOI CMOS **			13						18			

\* Process modules included for metal 6 option : LP MOS, MET3, MET4, METMID, METTHK, MRPOLY, ISOMOS, LVT, DMOS, HV MOS, SCHOTTKY, MIM, NVM, FLASH, OTP3, PHOTODIO.

\*\* Process modules included for metal 6 option : LP5MOS, HVN, HVP, 1XN, 1XP, PSUB, DTI, DNC, DPC, NBUR, HRPOLY, MIMH, MET3, MET4, METMID, METTHK, HWC.

TSMC	J	F	M	A	M	J	J	A	S	O	N	D
TSMC 0.18 CMOS General Logic or MS/RF (MIM: 2.0 fFum <sup>2</sup> / UTM: 20kÅ)	31				17				27			
TSMC 0.18 CMOS High Voltage BCD Gen 2					31				27			
TSMC 90nm CMOS LP MS RF		22				21				25		
TSMC 65nm CMOS LP MS RF		15			24			23			22	
TSMC 40nm CMOS LP MS RF		8				14				18		
TSMC 28nm CMOS HPL RF (reserve 4 months in advance)		22										
TSMC 28nm CMOS HPC RF (reserve 4 months in advance)				26						25		

options TSMC mini@sic runs	IO	MIM /um <sup>2</sup>	special remarks
TSMC 0.18μ CMOS MS/RF	3.3 V	2 fF	6 metals with UTM (20kA) topmetal
TSMC 0.18 CMOS High Voltage BCD Gen 2 0.18 μm CMOS High Voltage Mixed Signal based General Purpose BCD Dual Gate FSG AL 1P6M [SALICIDE, NBL/PBL EPI, 1.8/5/6/8/12/16/20/24/29/36/45/55/65/70V/Vg1.8/5VV]		2 fF between M5 & M6	6 metals with UTM (30kA) topmetal
TSMC 90nm CMOS LP MS RF	2.5V	2 fF	Core : 1.2 V, Metal scheme : 1P9M_6X1N1U Default : wirebond with 14kA thick RDL. AP layer mandatory in bondpads.
TSMC 65nm CMOS LP MS RF	2.5V (1.8UD, 3.3OD)	2 fF	Core : 1.2 V, Metal scheme : 1P9M_6X1Z1U_RDL Default : wirebond with 14kA thick RDL. AP layer mandatory in bondpads.
TSMC 40nm CMOS LP MS RF – No Triple Gate oxide	2.5V (1.8UD, 3.3OD)	-	Core : 1.1 V, Metal scheme : 1P8M_5X2Z_RDL Default : wirebond with 14kA thick RDL. AP layer mandatory in bondpads.
TSMC 28nm CMOS HPL – High Performance Low Leakage, RF	1.8 V	-	Core : 1.0 V, Metal scheme : 1P8M_5X1Z1U UTRDL (28kA thick AP layer) Default: BEOL option 1, 10 mils backlapping
TSMC 28nm CMOS HPC – High Performance Compact Mobile Computing, RF	1.8 V	-	Core : 0.9 V, Metal scheme : 1P8M_5X1Z1U UTRDL (28kA thick AP layer) Default: BEOL option 1, 10 mils backlapping

UMC	J	F	M	A	M	J	J	A	S	O	N	D
UMC L65N Logic/Mixed-Mode/RF - LL	30			24			24			23		
UMC L130 Mixed-Mode/RF		27				19				30		
UMC L180 Mixed-Mode/RF	23		20		30		17		25		27	
UMC 40nm Logic/Mixed-Mode/LP						5				16		

Run has been cancelled by UMC.

options UMC mini@sic runs	Core	IO	MIM	topmetal	special remarks
UMC L65N Logic/Mixed-Mode-MODE65N/RF - LL - 1P8M1T0F1U - 1.2V/2.5V	1.2	2.5V/2.5V_OD3.3V	2fF	32.5kA	Metal-stack "26"
UMC L130 Mixed-Mode/RF - 1P8M2T - 1.2V/3.3V	1.2V	3.3V	1fF	20kA	Possible combinations: HS, HS-LL (No SP possible)
UMC L180 Mixed-Mode/RF - 1P6M - 1.8V/3.3V	1.8V	3.3V	1fF	20kA	
UMC 40nm LP Logic/MS	This is work in progress. Target to get it fully settled mid January				

GLOBALFOUNDRIES	J	F	M	A	M	J	J	A	S	O	N	D
GLOBALFOUNDRIES 55 nm LPe			13						18			
GLOBALFOUNDRIES 40 nm LP/LP-RF/RF-mmWave				3						2		
GLOBALFOUNDRIES 28 nm SLP/SLP-RF					8						6	
GLOBALFOUNDRIES 22 nm FDSOI										16		

**Important Note:** Dates are registration deadlines after which designs cannot enter this MPW run anymore. Final GDSII file must be submitted within 6 weeks after this date.

## 2017 mini@sic Europractice MPW runs – Pricelist

Accessible for universities, research institutes and companies  
 Prices and conditions may change at any time without prior notice  
**Prices valid for runs starting 1 January 2017.**

**NON-EUROPEAN** price applies to all non-European (not belonging to the countries of EUROPEAN price) universities and research institutes who submit designs for **educational or publicly funded research use only.**

**EUROPEAN** price : only applies to EUROPRACTICE registered (who paid their annual full membership fee) Academic and Research Members from all 28 EU countries and Albania, Armenia, Azerbaijan, Belarus, Bosnia-Herzegovina, Georgia, Iceland, Israel, Liechtenstein, Former Yugoslav Republic of Macedonia, Moldova, Montenegro, Norway, Russia, Switzerland, Turkey, Serbia and Ukraine who submit designs for **educational or publicly funded research use only.**

**For the following technologies, there are special discounted prices thanks to a special grant through the EU-Project EUROPRACTICE 2016 in the H2020 Framework : ams 0.35μm and 0.18μm, IHP SG25Hx and SG13x, TSMC 0.18μm, 90, 65, 40 & 28nm, UMC 180, 130, 65 & 40nm, XFAB XH018 & XT018, GLOBALFOUNDRIES 55, 40, 28 & 22nm and On Semi 0.7 and 0.35μm.**

Prices are given for the delivery of unpacked, untested prototypes. Encapsulation and testing will be charged separately.

### Number of prototypes

OnSemi > 20 samples  
 ams : 40 samples  
 UMC : 0.18um, 0.13um : 25 samples  
 UMC : 65nm, 40nm : 45 samples  
 IHP : 40 samples SG25 & SG13, 20 samples PIC, EPIC & MEMS  
 XFAB : 15 samples  
 TSMC : 40 samples for 0.18u, 100 samples for 90 ... 28nm  
 GLOBALFOUNDRIES : 50 samples  
 If you need more prototype samples, please ask for a quotation

### Plots

You can order plots/PDF of your designs  
 - first plot/PDF costs 50 euro  
 - next plots cost 20 euro each

**Packaging** : see separate prices and available packages

**ALL PRICES IN EURO**

<b>ON Semiconductor (formerly AMIS)</b>	<b>NON-EUROPEAN Price/mm<sup>2</sup></b>	<b>EUROPEAN Price/mm<sup>2</sup></b>
ON Semi 0.7μ C07M-D 2M/1P	300 <sup>2</sup>	270 <sup>2</sup>
ON Semi 0.7μ C07M-A 2M/1P/PdiffC/HR	350 <sup>2</sup>	315 <sup>2</sup>
ON Semi 0.7μ C07M-I2T100 100 V - 2M	525 <sup>2</sup>	485 <sup>2</sup>
ON Semi 0.7μ C07M-I2T100 100 V - 3M	560 <sup>2</sup>	525 <sup>2</sup>
ON Semi 0.35μ C035U 4M (default) including analog options	720 <sup>2</sup>	670 <sup>2</sup>
ON Semi 0.35μ C035U 3M (optional) including analog options	700 <sup>2</sup>	650 <sup>2</sup>
ON Semi 0.35μ C035U 5M (optional) including analog options	800 <sup>2</sup>	750 <sup>2</sup>
ON Semi 0.35μ C035 - I3T80U 80 V 3M	850 <sup>2</sup>	800 <sup>2</sup>
ON Semi 0.35μ C035 - I3T80U 80 V 4M	925 <sup>2</sup>	875 <sup>2</sup>
ON Semi 0.35μ C035 - I3T80U 80 V 5M	1050 <sup>2</sup>	995 <sup>2</sup>
ON Semi 0.35μ C035 - I3T50U (or E) 50 V 3M	850 <sup>2</sup>	800 <sup>2</sup>
ON Semi 0.35μ C035 - I3T50U (or E) 50 V 4M	925 <sup>2</sup>	875 <sup>2</sup>
ON Semi 0.35μ C035 - I3T50U (or E) 50 V 5M	1050 <sup>2</sup>	995 <sup>2</sup>
ON Semi 0.35μ C035 - I3T25U 3.3/25 V 3M (optional)	750 <sup>2</sup>	700 <sup>2</sup>
ON Semi 0.35μ C035 - I3T25U 3.3/25 V 4M (default)	770 <sup>2</sup>	720 <sup>2</sup>
ON Semi 0.35μ C035 - I3T25U 3.3/25 V 5M (optional)	800 <sup>2</sup>	750 <sup>2</sup>

<b>ams</b>	<b>NON-EUROPEAN Price/mm<sup>2</sup></b>	<b>EUROPEAN Price/mm<sup>2</sup></b>
ams 0.35μ CMOS C35B4C3 4M/2P/HR/5V IO	640 <sup>2</sup>	580 <sup>2</sup>
ams 0.35μ CMOS C35OPTO 4M/2P/5V IO	800 <sup>2</sup>	700 <sup>2</sup>
ams 0.35μ HV CMOS H35B4D3 120V 4M	880 <sup>2</sup>	800 <sup>2</sup>
ams 0.35μ SiGe-BiCMOS S35 4M/4P	880 <sup>2</sup>	800 <sup>2</sup>
ams 0.18μ CMOS aC18 6M/1P/MIM/1.8V/5V	1100 <sup>2</sup>	1050 <sup>2</sup>
ams 0.18μ HV CMOS aH18 50V/20V/5V/1.8V/ 6M/MIM	1150 <sup>2</sup>	1100 <sup>2</sup>
Bottom Anti Reflective Coating (BARC) Diode for ams 0.35μ CMOS C35OPTO 4M/2P/5V IO	One-off extra fee of 6900	One-off extra fee of 4500
Wafer Level Chip Scale Package for ams 0.35μ CMOS C35B4C3 4M/2P/HR/5V IO	One-off extra fee of 6250	One-off extra fee of 4000

<b>IHP</b>	<b>NON-EUROPEAN Price/mm<sup>2</sup></b>	<b>EUROPEAN Price/mm<sup>2</sup></b>
IHP SGB25V 0.25μ SiGe:C Ft=75GHz@BVCEO 2.4V	2125 <sup>4</sup>	1940 <sup>4</sup>
IHP SG25H3 0.25μ SiGe:C Ft/Fmax= 110/180GHz 5M/MIM	3230 <sup>4</sup>	2950 <sup>4</sup>
IHP SG25H4 0.25μ SiGe:C Ft/Fmax= 200/220GHz 5M/MIM	3910 <sup>4</sup>	3220 <sup>4</sup>
SG25H EPIC (based on SG25H4)	5610 <sup>4</sup>	3960 <sup>4</sup>
IHP SG13G2 SiGe:C Bipolar/Analog Ft/Fmax= 300/500GHz 7M/MIM	6205 <sup>4</sup>	5110 <sup>4,6</sup>
IHP SG13S SiGe:C Bipolar/Analog/CMOS Ft/Fmax= 250/300GHz 7M/MIM	5355 <sup>4</sup>	4410 <sup>4</sup>
IHP SG13C SiGe:C CMOS 7M/MIM	3825 <sup>4</sup>	3375 <sup>4</sup>
IHP SG25 PIC (Photonics devices, Ge Photo-diode, BEOL)	1700 <sup>4</sup>	1200 <sup>4</sup>

<b>X-FAB</b>	<b>NON-EUROPEAN Price/block</b>	<b>EUROPEAN Price/block</b>
X-FAB XH018 0.18μ HV NVM CMOS E-FLASH (MET3, MET4, METMID, METTHK)	3950 <sup>7</sup>	3765 <sup>7</sup>
X-FAB XT018 0.18μ HV SOI CMOS (MET3, MET4, METMID, METTHK)	4040 <sup>7</sup>	3840 <sup>7</sup>

<b>TSMC</b>	<b>NON-EUROPEAN Price/block</b>	<b>EUROPEAN Price/block</b>
TSMC 0.18 CMOS General Logic or MS/RF	3840 <sup>13</sup>	3650 <sup>13</sup>
TSMC 0.18 CMOS High Voltage BCD Gen 2	5420 <sup>23</sup>	5150 <sup>23</sup>
TSMC 90nm CMOS LP MS RF	11880 <sup>14</sup>	11290 <sup>14</sup>
TSMC 65nm CMOS LP MS RF	15500 <sup>14</sup>	14730 <sup>14</sup>
TSMC 40nm CMOS LP MS RF	20840 <sup>12</sup>	19800 <sup>12</sup>
TSMC 28nm CMOS HPL RF	22470 <sup>22</sup>	21350 <sup>22</sup>
TSMC 28nm CMOS HPC RF	23130 <sup>22</sup>	21980 <sup>22</sup>

<b>UMC</b>	<b>NON-EUROPEAN Price/block</b>	<b>EUROPEAN Price/block</b>
UMC L180 Mixed-Mode/RF - 1P6M - 1.8V/3.3V	3120 <sup>8</sup>	2970 <sup>8</sup>
UMC L130 Mixed-Mode/RF - 1P8M2T - 1.2V/3.3V	5250 <sup>8</sup>	4990 <sup>8</sup>
UMC L65N Logic/Mixed-Mode LL & L65N Logic/Mixed-Mode SP	10470 <sup>9</sup>	9950 <sup>9</sup>
UMC 40nm LP Logic/Mixed Mode/RF	20180 <sup>9</sup>	19180 <sup>9</sup>

<b>GLOBALFOUNDRIES</b>	<b>NON-EUROPEAN Price: see notes</b>	<b>EUROPEAN Price: see notes</b>
GLOBALFOUNDRIES 55 nm LPe	18500 & 4000 <sup>17, 16, 26</sup>	13900 & 3800 <sup>15, 16</sup>
GLOBALFOUNDRIES 40 nm LP/LP-RF/RF-mmWave	23750 & 5000 <sup>19, 16, 26</sup>	17850 & 4700 <sup>18, 16</sup>
GLOBALFOUNDRIES 28 nm SLP	46800 & 10200 <sup>21, 16, 26</sup>	29100 & 9700 <sup>20, 16</sup>
GLOBALFOUNDRIES 22 nm FDSOI	65000 & 14700 <sup>25, 16, 26</sup>	42000 & 14000 <sup>24, 16</sup>

## Notes

- 1) Price = area (mm<sup>2</sup>) \* price/mm<sup>2</sup> with min. fabrication cost equivalent to 3 mm<sup>2</sup>
- 2) Price = area (mm<sup>2</sup>) \* price/mm<sup>2</sup> with min. fabrication cost equivalent to 4 mm<sup>2</sup>
- 3) Price = area (mm<sup>2</sup>) \* price/mm<sup>2</sup> with min. fabrication cost equivalent to 5 mm<sup>2</sup>
- 4) Price = area (mm<sup>2</sup>) \* price/mm<sup>2</sup> with min. fabrication cost equivalent to 0.8 mm<sup>2</sup>
- 5) Minimum charged area = 5 mm<sup>2</sup>.  
For area ≤ 5 mm<sup>2</sup>, Price = 5000 euro  
For area > 5 mm<sup>2</sup>, Price = 5000 + (area-5) \* 1100
- 6) Minimum charged area = 0.8 mm<sup>2</sup>  
For area ≤ 0.8 mm<sup>2</sup>, Price = 3270 euro  
For area > 0.8 mm<sup>2</sup>, Price = 3270 + (area-0.8)\*5110
- 7) Price = per block of 1520x1520 microns needed to fit the design in. Adding two blocks together to one block is possible.
- 8) Price = per block of 1525x1525 microns needed to fit the design in. Adding two blocks together to one block is possible.
- 9) Price = per block of 1875x1875 microns needed to fit the design in. Adding two blocks together to one block is possible.
- 10) Minimum charged area = 4 mm<sup>2</sup>.  
For area ≤ 4 mm<sup>2</sup>, Price = 3200 euro  
For area > 4 mm<sup>2</sup>, Price = 3200 + (area-4) \* 880
- 11) Price = per submitted design to be bumped (no size limit, limited to 200 bumps)
- 12) Price = per block of 1920x1920 microns (designed area – pre-shrink) needed to fit the design in, (on silicon area – after shrink = 1730x1730 microns) – see below
- 13) Price = per block of 1660x1660 microns needed to fit the design in
- 14) Price = per block of 2000x2000 microns needed to fit the design in
- 15) Minimum charged area = 3 mm<sup>2</sup>. For area ≤ 3 mm<sup>2</sup>, Price = 13900 euro. For area > 3 mm<sup>2</sup>, Price = 13900 + (area-3) \* 3800
- 16) Any edge length between 1.0 mm to 12.5 mm is possible. The mentioned die size is referred to the Pre-Shrink die size
- 17) Minimum charged area = 4 mm<sup>2</sup>. For area ≤ 4 mm<sup>2</sup>, Price = 18500 euro. For area > 4 mm<sup>2</sup>, Price = 18500 + (area-4) \* 4000
- 18) Minimum charged area = 3 mm<sup>2</sup>. For area ≤ 3 mm<sup>2</sup>, Price = 17850 euro. For area > 3 mm<sup>2</sup>, Price = 17850 + (area-3) \* 4700
- 19) Minimum charged area = 4 mm<sup>2</sup>. For area ≤ 4 mm<sup>2</sup>, Price = 23750 euro. For area > 4 mm<sup>2</sup>, Price = 23750 + (area-4) \* 5000
- 20) Minimum charged area = 3 mm<sup>2</sup>. For area ≤ 3 mm<sup>2</sup>, Price = 29100 euro. For area > 3 mm<sup>2</sup>, Price = 29100 + (area-3) \* 9700
- 21) Minimum charged area = 4 mm<sup>2</sup>. For area ≤ 4 mm<sup>2</sup>, Price = 46800 euro. For area > 4 mm<sup>2</sup>, Price = 46800 + (area-4) \* 10200
- 22) Price = per block of 1570x1570 microns (designed area – pre-shrink) needed to fit the design in, (on silicon area – after shrink = 1413x1413 microns) – see below
- 23) Price = per block of 2500x2500 microns needed to fit the design in
- 24) Minimum charged area = 3 mm<sup>2</sup>. For area ≤ 3 mm<sup>2</sup>, Price = 42000 euro. For area > 3 mm<sup>2</sup>, Price = 42000 + (area-3) \* 14000
- 25) Minimum charged area = 4 mm<sup>2</sup>. For area ≤ 4 mm<sup>2</sup>, Price = 65000 euro. For area > 4 mm<sup>2</sup>, Price = 65000 + (area-4) \* 14700
- 26) We reserve the right to cancel mini@sic runs if the run is not economically feasible.

### **UMC 0.18 and 0.13µ mini@sic rules**

In this case however the standard block of 5x5 mm is subdivided into 9 regular square sub-blocks. Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 1525 x 1525 µm
- 2 sub-blocks : design may not be larger than 3240 x 1525 µm
- 3 sub-blocks : design may not be larger than 4960 x 1525 µm
- 4 sub-blocks : design may not be larger than 3240 x 3240 µm
- 6 sub-blocks : design may not be larger than 4960 x 3240 µm

The price for prototyping is the number of sub-blocks your design needs to fit in, multiplied with the sub-block price.

### **UMC 90nm & 65nm mini@sic rules**

Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 1875 x 1875 µm
- 2 sub-blocks : design may not be larger than 3950 x 1875 µm

### **TSMC 90nm & 65nm mini@sic rules**

Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 2000 x 2000 µm
- 2 sub-blocks : design may not be larger than 4000 x 2000 µm

### **TSMC 40nm mini@sic rules**

Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 1920 x 1920 µm (pre-shrink)
- 2 sub-blocks : design may not be larger than 3840 x 1920 µm
- These are designed dimensions. Fabricated designs (40nm) are shrunked during maskmaking in both X and Y directions by 0.9

### **TSMC 28nm mini@sic rules**

Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 1570 x 1570 µm (pre-shrink)
- 2 sub-blocks : design may not be larger than 3140 x 1570 µm
- These are designed dimensions. Fabricated designs (28nm) are shrunked during maskmaking in both X and Y directions by 0.9

### **TSMC 0.18µ CMOS mini@sic rules**

In this case however the standard block of 5x5 mm is subdivided into 9 regular square sub-blocks. Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 1660 x 1660 µm
- 2 sub-blocks : design may not be larger than 3320 x 1660 µm
- 3 sub-blocks : design may not be larger than 4980 x 1660 µm
- 4 sub-blocks : design may not be larger than 3320 x 3320 µm
- 6 sub-blocks : design may not be larger than 4980 x 3320 µm

### **TSMC 0.18µ HV BCD mini@sic rules**

Users under the *mini@sic* program can submit single or multiple of sub-blocks depending on the size of their design.

- single sub-block : design may not be larger than 2500 x 2500 µm
- 2 sub-blocks : design may not be larger than 5000 x 2500 µm

The price for prototyping is the number of sub-blocks your design needs to fit in, multiplied with the sub-block price.

## **Contacts**

**imec**, Belgium (P. Malisse, tel: +32 16 281272, e-mail: mpc@imec.be)

**Fraunhofer IIS**, Germany (W. McKinley, tel : +49 9131 776 4413, e-mail: europac@iis.fraunhofer.de)